Attorney Docket No. ASC-049C1

E UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT(S):

Fitzgerald

**SERIAL NO.:** 

10/774,890

**GROUP NO.:** 

2818

FILING DATE:

February 9, 2004

**EXAMINER:** 

Tran, Mai Huong C.

**PATENT** 

TITLE:

RELAXED SiGe PLATFORM FOR HIGH SPEED CMOS

**ELECTRONICS AND HIGH SPEED ANALOG CIRCUITS** 

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Sir:

In accordance with the provisions of 37 C.F.R. 1.97 and 1.98, Applicants hereby make of record the patents and publications listed on the accompanying Form PTO-1449, and other information contained herein, for consideration by the Examiner in connection with the examination of the above-identified patent application. In accordance with the U.S. Patent Office's partial waiver of the requirement under 37 C.F.R. 1.98(a)(2)(i), only copies of the non-patent publications are enclosed.

### REMARKS

In accordance with the provisions of 37 C.F.R. 1.97, this statement is being filed (CHECK ONE):

(1)	within three (3) months of the filing date of a national application other than a continued prosecution application under 37 C.F.R. 1.53(d), or within three (3) months of the date of entry of the national stage as set forth in 37 C.F.R. 1.491 in an international application, or before the mailing of the first Office action on the merits, or before the mailing of a first Office action after the filing of a request for continued examination under 37 C.F.R. 1.114; or				
(2)	after the period defined in (1) but before the mailing date of a final action or a notice of allowance under 37 C.F.R. 1.311, and				
	the requisite Statement is below, OR				
	the requisite fee under 37 C.F.R. 1.17(p), namely \$180.00, is included herein, or				

Supplemental Information Disclosure Statement Serial No. 10/774,890 Page 2 of 2

(3)	after the mailing date of a final action or notice of allowance but before the payment of the issue fee, AND				
	the requisite Statement is below, AND				
the requisite petition fee under 37 C.F.R. 1.17(p), namely \$180.00 is					
•	ally requested that each of the patents and publications listed on the attached Form PTO-formation contained herein, be made of record in this application.				
	Respectfully submitted,				
uly 7, 2005 5. 44,381	Natasha C. Us Attorney for Applicant(s) Goodwin Procter LLP				
.: (617) 57 : (617) 52:	0-1806 Exchange Place				



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## CERTIFICATE OF FIRST CLASS MAILING UNDER 37 C.F.R. 1.8

I hereby certify that this correspondence, and any document(s) referred to as enclosed herein, is/are being deposited with the United States Postal Service as first class mail, postage prepaid, in an envelope addressed to the Mail Stop Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on this 7<sup>th</sup> day of July, 2005.

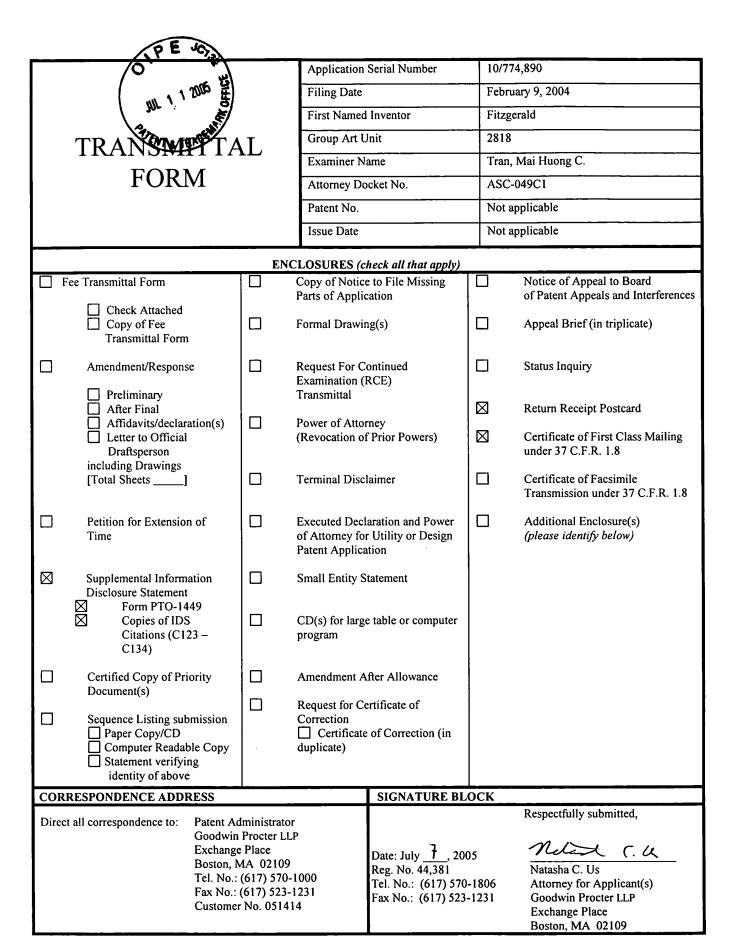
Wendy L. Martin

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

#### Submitted herewith are:

- 1. Transmittal Form (1 page);
- 2. Supplemental Information Disclosure Statement (2 pages);
- 3. Form PTO 1449 (1 page);
- 4. Copies of cited references (C123 C134);
- 5. Return receipt postcard



# **FORM PTO – 1449**

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

ATTORNEY DOCKET NO.: ASC-049C1

APPLICANT(S): Fitzgerald

SERIAL NO.: 10/774,890

FILING DATE: February 9, 2004

TIME TRIES					GROUP: 2818				
			U.S. P	ATENT	DOCUMENTS				
EXAM. INIT.		DOCUMENT NUMBER	DATE	NAME		CLASS	SUB CLASS	FILING DATE IF APPROPRIATE	
	A191	2003/0080361 A1	05/01/2003	Murthy et al.  Crabbé et al.  Chin et al.					
	A192	5,821,577	10/13/1998						
	A193	6,350,311 B1	02/26/2002						
,		O	THER ART,	JOUR	NAL ARTICLES	, ETC.		-	
EXAM. INIT.	ОТНІ	ER DOCUMENTS:	(Including Au	thor, Tit	le, Date, Relevant Pa	iges, Place of	f Publication	on)	
	C123	Examination Report for European Patent Application No. 98 931 529.6-2203, dated January 10, 2002, 4 pages.							
	C124	Examination Report	for European F	Patent Ap	plication No. 98 931	529.6-2203,	dated May	9, 2003, 5 pages.	
	C125 Examination Report for European Patent Application No. 01 973 651.1-1528, dated March 22, 2004								
	C126	pages.							
	C127								
	C128 Examination Report for European Patent Application No. 02 709 406.9-2203, dated May 11, 2004, 3 pag C129 Examination Report for European Patent Application No. 02 709 406.9-2203, dated March 24, 2005, 5 pages C130 International Search Report for Patent Application No. PCT/US 98/13076, dated October 27, 1998, 2 page C131 Notice of Preliminary Rejection for Korean Patent Application No. 10-1999-7012279, dated February 21, 2002, 2 pages (English translation attached). C132 Notice of Final Rejection for Korean Patent Application No. 10-1999-7012279, dated February 25, 2003 pages (English translation attached). C133 Klauk et al., "Thermal stability of undoped strained Si channel SiGe heterostructures," Applied Physics Letter, No. 68, April 1, 1996, pgs. 1975-1977. C134 Rim et al., "Enhanced Hole Mobilities in Surface-channel Strained-Si- p-MOSFETs," IEEE (1995), pg. 20.3.1-20.3.4.								
			<u> </u>		<u> </u>				
EXAMINER					DATE CONSIDI	ERED			